

Features

• 10 to 50 MHz input frequency ranges

• Operating voltages of 1.62 V to 3.63V

• Spreading Ratio: -2.0%,-1.5%,-1.0%,-0.8%

• Modulation Rate: Fin / 764

· Low power consumption and dissipation

Applications

• IP Camera

• Printers/MFPs

· Media players

• DTV/Set-top Box

• Embedded digital video devices

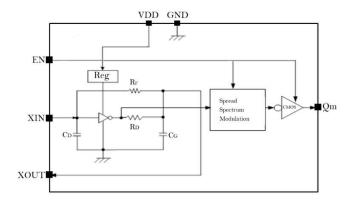
· LCD Panel Modules

• Automotive components

· Networking devices

• Surveillance

Block Diagram



Description

The RS1XOS6201-xxZAE is one Low Power Spread Spectrum Frequency Multiplier part of RSM SSC family. The output frequency is same as crystal, and is designed to reduce electromagnetic interference (EMI) by spreading the clock.

The Spreading Mode/Ratio is programmed in fab by ROM codes. The RS1XOS6201-xxZAE provides spread, refer to different option.

Benefits

- · Reduction in EMI
- · System cost saving
- · Reduced system complexity
- · Faster time to market

Order Information

Part no.	Package type
RS1XOS6201-xxZAE	DFN2*2-8L

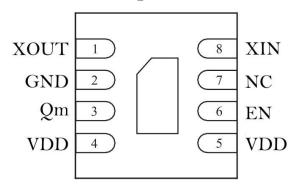
Note:

xx: -AC: -2%, AE: -1.5%, AF: -1%, BF: -0.8%



Pin Function

Top View



Pad Description

ad Description			
Pin Name	I/O Type	Description	
		Output Enable/Disable or Spreading Enable/Disable control by 3 states;	
OE	I	Low: Qm output Hiz;	
OE	1	High: Qm output with spreading	
		>VDD + 1V: Qm output without spreading.	
X _{IN}	I	Crystal input pad.	
X _{OUT}	О	Crystal output pad.	
GND	GND	Ground.	
Qm	О	Spread spectrum clock output (OE=VDD).	
v_{DD}	Power	Power supply.	



Maximum Rating

Supply Voltage to Ground Potential4	V
OE pinVDD+2	
Other Inputs and OutputVDD+0.5	
Storage Temperature65°C to +150)°C

Note:

Stresses greater than those listed under MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sec-tions of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

Recommended Operating Conditions

(GND=0V, unless otherwise noted.)

Sym.	Parameter	Conditions	Min	Тур	Max	Unit
V_{DD}	Supply voltage	-	1.62	-	3.63	V
T_A	Operating temperature	-	-40		+125	°C
f_0	Oscillation frequency*1	-	16	27	40	MHz

DC Characteristics

VDD= 1.62V to 3.63V, Ambient Temperature -40 to +125°C

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Unit
V _{DD}	Operating voltage	-	1.62	_	3.63	V
		VDD=1.8V, IOH = -1mA	VDD-0.4			V
$ m V_{OH}$	Output high voltage	V _{DD} =2.5V, I _{OH} = -1mA	VDD-0.4	_	_	V
		V _{DD} =3.3V, I _{OH} = -1mA	VDD-0.4	_	_	V
		VDD=1.8V, IOL = 1mA			0.4	V
V_{OL}	Output low voltage	$V_{DD}=2.5V$, $I_{OL}=1$ mA	_	_	0.4	V
		VDD=3.3V, $IOL=1mA$	_	_	0.4	V
V_{IH}	HIGH-level input voltage	OE Measurement	0.7VDD			V
$V_{\rm IL}$	LOW-level input voltage	OE Measurement			0.3VDD	V
		VDD=1.8V, OE=VDD;27MHz/15pf		2	4	mA
IDD1	Supply current1	VDD=2.5V, OE=VDD;27MHz/15pf		2.5	5	mA
		VDD=3.3V, OE=VDD;27MHz/15pf		3.0	6	mA
		VDD=1.8V, OE>VDD+1V,27MHz/15pf		1.3	3	mA
IDD2	Supply current2	V _{DD} =2.5V, OE>VDD+1V,27MHz/15pf		1.7	3.5	mA
		VDD=3.3V, OE>VDD+1V,27MHz/15pf		2.1	4	mA

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AC Characteristics

VDD= 1.62V to 3.63V, Ambient Temperature -40 to +125°C

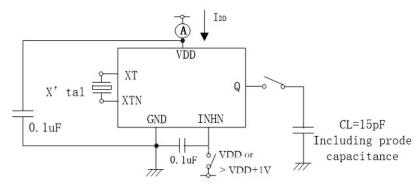
Symbol	Parameter	Conditions	Min.	Тур.	Max.	Unit
XIN, XOUT	Crystal frequency range		10	_	50	MHz
		Measured from 20% to 80% VDD=1.8V, Load=15pf		2.4	5	ns
t _{Rise}	Output rise time	Measured from 10% to 90% VDD=2.5V, Load=15pf		2.4	5	ns
		Measured from 10% to 90% VDD=3.3V, Load=15pf	I	2	5	ns
		Measured from 80% to 20% VDD=1.8V, Load=15pf		2.6	5	ns
t _{Fall}	Output fall time	Measured from 90% to 10% VDD=2.5V, Load=15pf		2.4	5	ns
		Measured from 90% to 10% VDD=3.3V, Load=15pf	-	2	5	ns
Duty cycle	Output duty cycle	Load=15pf, 50%VDD	45	50	55	%

Note: Typical condition is on room temperature at 25°



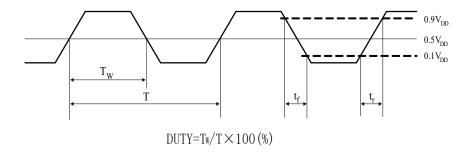
Measurement Circuit

Measurement parameter: IDD, Duty, tr, tf

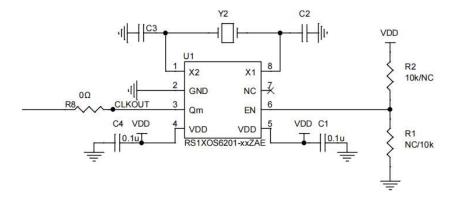


Note: The AC characteristics are observed using an oscilloscope on pin Q

Output switching waveform



Application Circuit

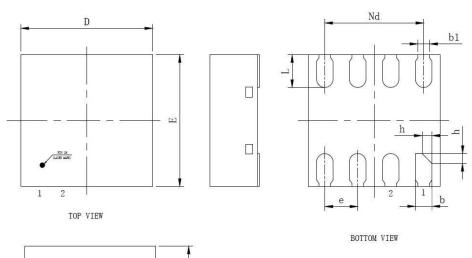


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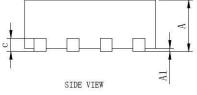


Package Dimension

DFN 2X2X0.75-8L(0.5 pitch) ZA08



exa mor	MILLIMETER		
SYMBOL	MIN	NOM	MAX
A	0.70	0.75	0.80
A1	0	0.02	0. 05
b	0.18	0.25	0.30
b1	0.18REF		
С		0.203REF	7
D	1. 90	2. 00	2. 10
e	0. 50BSC		
Nd	1. 50BSC		
E	1. 90	2. 00	2. 10
L	0. 45	0.50	0. 55
h	0. 10	0. 15	0. 20



Notes:

- 1. All dimensions are in mm. Angles in degrees.
- 2. Refer JEDEC MO-229
- 3. Dimensions exclude burrs, mold flash or protrusions.



DFN2X2X0.75-8L (ZA08) POD

Raystar Microelectronics Technology Inc.

Revision History

Revision	Description	Date
0	Initiated	2023/5/25
1.0	Updated format and official release	2024/12/03
1.1	Add application circuitry, Add Order Information	2025/4/14
1.2	Updated production description	2025/8/13

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